



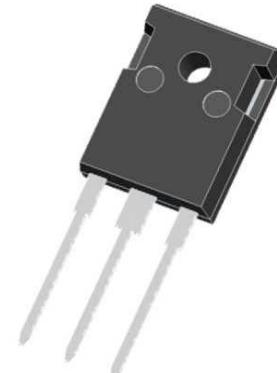
MUR6060PT

Ultra-Fast Recovery Diodes 30A*2 FRED Pt



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability



Typical Applications

- Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-247-3L
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked



	V _{RSM} V	V _{RRM} V
MUR6060PT	600	600

■Maximum Ratings (T_j=25°C Unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			600	V
I _{F(RMS)}	RMS forward voltage			60	A
I _{F(AV)}	Average forward current $\delta = 0.5$	T _c = 125°C	Per diode	30	A
		T _c = 110°C	Per device	60	
		T _c = 100°C	Per diode	40	
		T _c = 80°C	Per device	80	
I _{FSM}	Surge non repetitive forward current tp = 10ms sinusoidal			300	A
T _{stg}	Storage temperature range			-65 to + 175	°C
T _j	Maximum operating junction temperature			175	°C

Symbol	Parameter		Value (max.)	Unit
R _{th(j-c)}	Junction to case	Per diode	1.05	°C/W
		Total	0.68	
R _{th(c)}	Coupling		0.3	°C/W

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{\text{th}(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{\text{th}(c)}$$



■Electrical Characteristics

Symbol	Parameter	Test conditions		Min.	Typ	Max.	Unit
I_R *	Reverse leakage current	$T_j = 25^\circ C$	$V_R = V_{RRM}$			25	μA
		$T_j = 150^\circ C$			80	800	
V_F **	Forward voltage drop	$T_j = 25^\circ C$	$I_F = 30A$			1.65	V
		$T_j = 150^\circ C$			1.0	1.25	
		$T_j = 25^\circ C$	$I_F = 60A$			1.78	
		$T_j = 150^\circ C$			1.24	1.55	

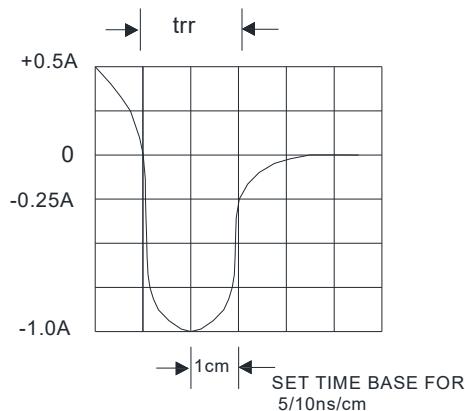
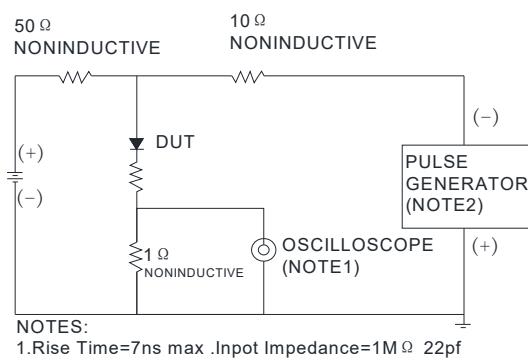
Pulse test: * $t_p = 5 \text{ ms}, \delta < 2\%$

** $t_p = 380 \mu\text{s}, \delta < 2\%$

To evaluate the conduction losses use the following equation: $P = 0.95 \times I_F(AV) + 0.010 I_F^2(\text{RMS})$

Symbol	Parameter	Test conditions			Min.	Typ	Max.	Unit
t_{rr}	Reverse recovery time	$T_j = 25^\circ C$	$I_F = 0.5A$	$I_{rr} = 0.25A$	$I_R = 1A$		65	ns
			$I_F = 1A$	$dI_F/dt = 50 \text{ A}/\mu\text{s}$	$V_R = 30V$		65	
I_{RM}	Reverse recovery current	$T_j = 125^\circ C$	$I_F = 30A$		$V_R = 400V$		11.5	16
t_{fr}	Forward recovery time	$T_j = 25^\circ C$	$I_F = 30A$		$dI_F/dt = 100 \text{ A}/\mu\text{s}$		500	ns
V_{FP}	Forward recovery voltage	$T_j = 25^\circ C$	$I_F = 30A$		$dI_F/dt = 100 \text{ A}/\mu\text{s}$		2.5	V
			$V_{FR} = 1.1 \times V_{Fmax}$					

FIG.5: Diagram of circuit and Testing wave form of reverse recovery time





■ Characteristics(Typical)

Figure 1: Conduction losses versus average forward current (per diode)

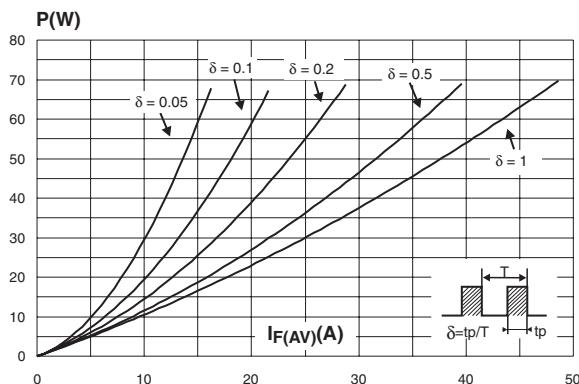


Figure 3: Relative variation of thermal impedance junction to case versus pulse duration

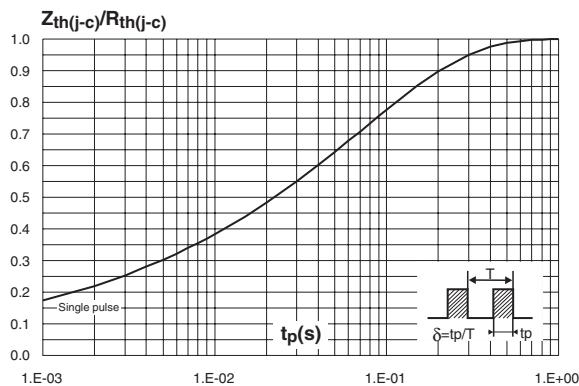


Figure 5: Reverse recovery time versus dI_F/dt (typical values, per diode)

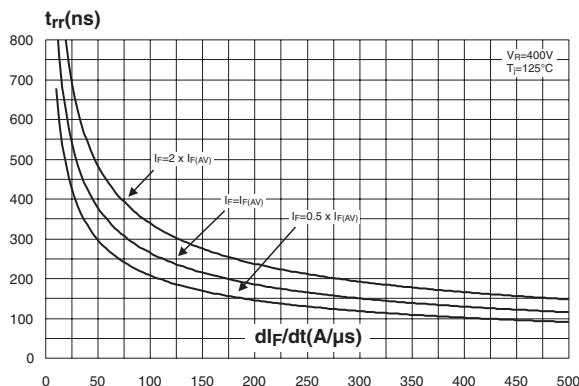


Figure 2: Forward voltage drop versus forward current (per diode)

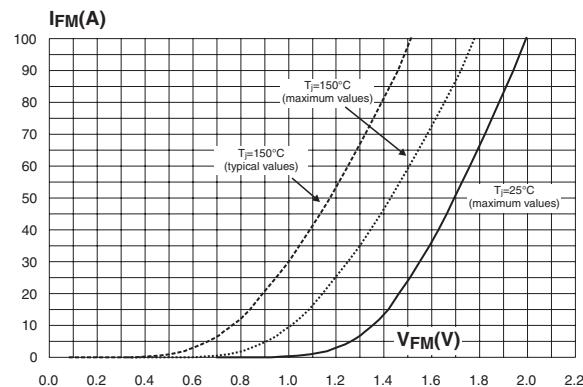


Figure 4: Peak reverse recovery current versus dI_F/dt (typical values, per diode)

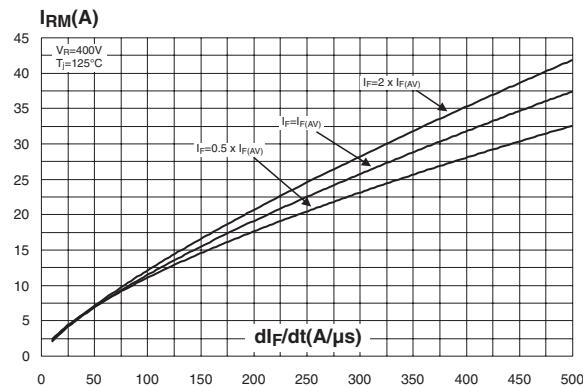


Figure 6: Reverse recovery charges versus dI_F/dt (typical values, per diode)

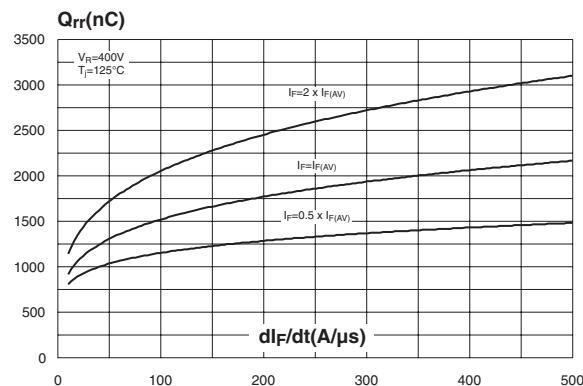




Figure 7: Reverse recovery softness factor versus dI_F/dt (typical values, per diode)

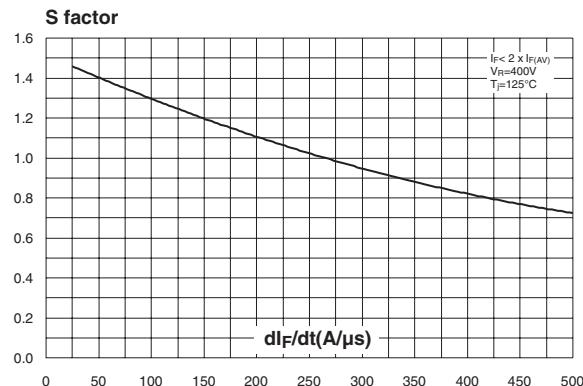


Figure 9: Transient peak forward voltage versus dI_F/dt (typical values, per diode)

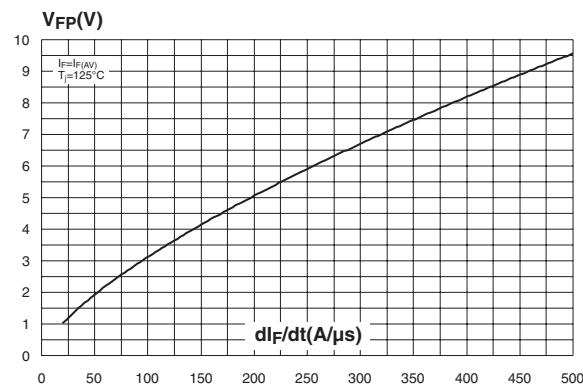


Figure 11: Junction capacitance versus reverse voltage applied (typical values, per diode)

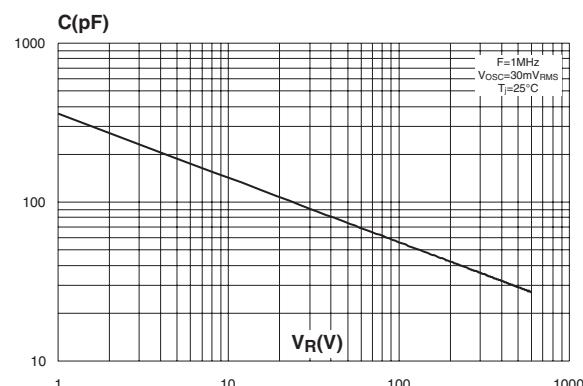


Figure 8: Relative variations of dynamic parameters versus junction temperature

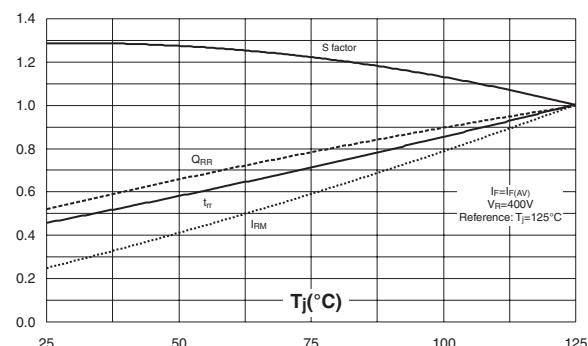
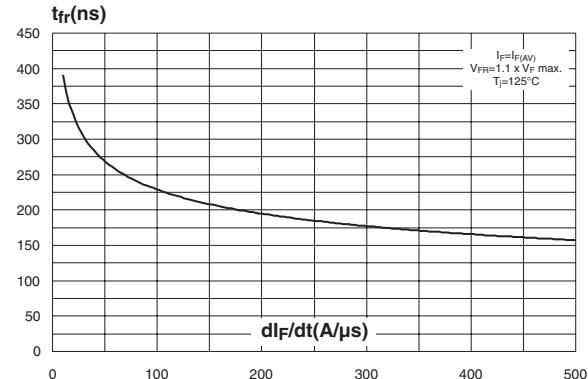
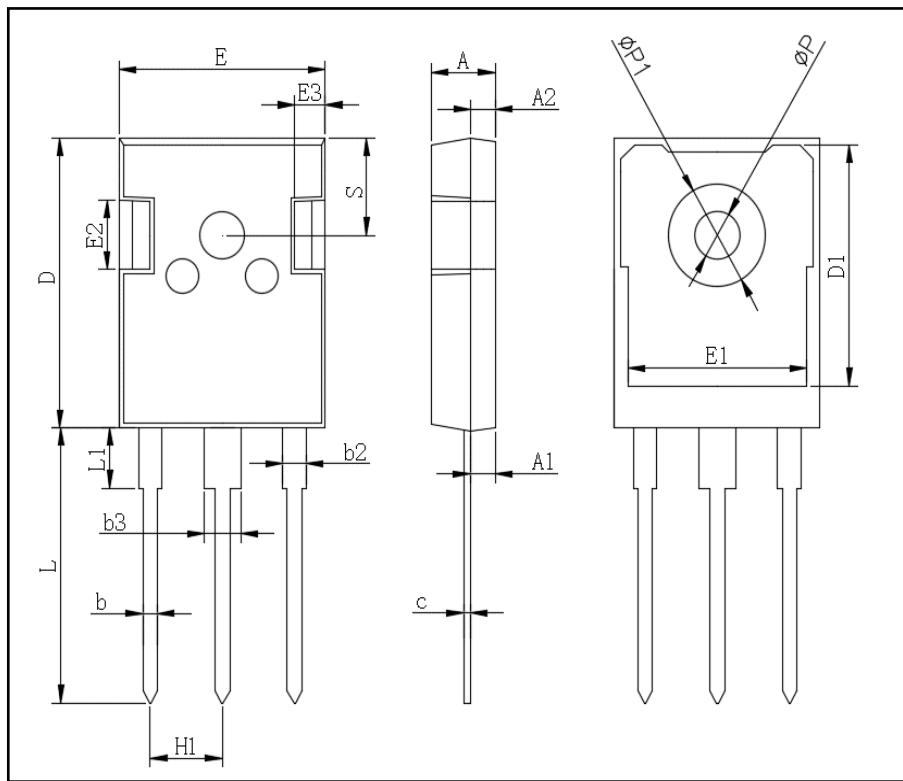


Figure 10: Forward recovery time versus dI_F/dt (typical values, per diode)





■ Outline Dimensions



TO-247-3L		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.0	1.4
b2	1.91	2.21
C	0.5	0.7
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.0	13.6
E2	4.80	5.20
E3	2.30	2.70
L	19.62	20.22
L1	-	4.30
φP	3.40	3.80
φP1	-	7.30
S	6.15TYP	
H1	5.44TYP	
b3	2.80	3.20

Packge	Packing	Box Size L×W×H(mm)	Quatity(pcs/box)	Carton Size L×W×H(mm)	Quatity(pcs/carton)
TO-247	30pcs/Tube	570×155×50	450	580×340×125	1800